



# ANALOG DEVICES

# 1.8 nV/ $\sqrt{\text{Hz}}$ , 36 V Precision Single and Dual Amplifier

Preliminary Technical Data

## ADA4004-1 and ADA4004-2

### FEATURES

**Very low voltage noise: 1.8 nV/ $\sqrt{\text{Hz}}$**

**Low input bias current: 100 nA maximum**

**Offset voltage: 100  $\mu\text{V}$  maximum**

**High gain: 120 dB**

**Wide bandwidth: 12 MHz**

**$\pm 5\text{ V}$  to  $\pm 15\text{ V}$  operation**

### APPLICATIONS

Precision instrumentation

Filter blocks

Microphone preamplifier

Industrial control

Thermocouples and RTDs

Reference buffers

### GENERAL DESCRIPTION

The ADA4004-1 and ADA4004-2 are single and dual precision bipolar op amps that featuring a 1.8 nV/ $\sqrt{\text{Hz}}$  precision, 40  $\mu\text{V}$  offset, 0.7  $\mu\text{V}/^\circ\text{C}$  drift, 12 MHz bandwidth, and low 1.7 mA/amplifier supply current.

The ADA4004 is designed on the high performance *iPolar*<sup>™</sup> process, enabling improvements such as reduced noise and power consumption, increased speed and stability, and a smaller footprint size. Novel design techniques enable the ADA4004 to achieve 1.8 nV/ $\sqrt{\text{Hz}}$  voltage noise density and a low 6 Hz 1/f noise corner frequency while consuming just 1.7 mA/amplifier. The small package saves board space, reduces cost, and improves layout flexibility.

Applications for these amplifiers include high precision controls, PLL filters, high performance precision filters, medical and analytical instrumentation, precision power supply controls, ATE, and data acquisition systems.

The high performance ADA4004 is offered in the very small 5-lead SOT and 8-lead SOIC for the single (ADA4004-1) and the 8-lead MSOP for the dual (ADA4004-2), lead-free, surface-mount packages. Operation is fully specified from  $\pm 5\text{ V}$  to  $\pm 15\text{ V}$  from  $-40^\circ\text{C}$  to  $+125^\circ\text{C}$ .

### PIN CONFIGURATIONS

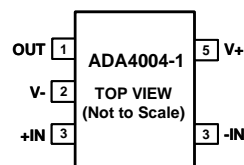


Figure 1.. 5-Lead SOT (RJ-5)

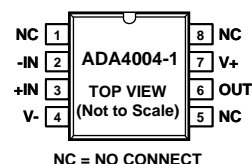
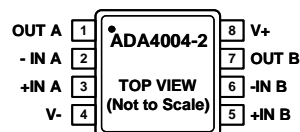


Figure 2. 8-Lead SOIC (R-8)



8-Lead MSOP (RM-8)

#### Rev. PrA

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**SPECIFICATIONS**

$V_S = \pm 5.0\text{ V}$ ,  $V_{CM} = 0\text{ V}$ ,  $T_A = +25^\circ\text{C}$ , unless otherwise specified.

Table 1.

Parameter	Symbol	Conditions	Min	Typ	Max	Unit
<b>INPUT CHARACTERISTICS</b>						
Offset Voltage	$V_{OS}$	$-40^\circ\text{C} \leq T_A \leq +125^\circ\text{C}$		40	140	$\mu\text{V}$
Input Bias Current	$I_B$	$-40^\circ\text{C} \leq T_A \leq +125^\circ\text{C}$		40	85	nA
Input Offset Current	$I_{OS}$	$-40^\circ\text{C} \leq T_A \leq +125^\circ\text{C}$		40	85	nA
Input Voltage Range		$-40^\circ\text{C} \leq T_A \leq +125^\circ\text{C}$	-3.5		+3.5	V
Common-Mode Rejection Ratio	CMRR	$V_{CM} = -3.0\text{ V to }+3.0\text{ V}$ $-40^\circ\text{C} \leq T_A \leq +125^\circ\text{C}$	105	111		dB
Open-Loop Gain	$A_{VO}$	$R_L = 2\text{ k}\Omega$ , $V_O = -2.5\text{ V to }+2.5\text{ V}$ $-40^\circ\text{C} \leq T_A \leq +125^\circ\text{C}$	250	400		V/mV
Offset Voltage Drift	$\Delta V_{OS}/\Delta T$	$-40^\circ\text{C} \leq T_A \leq +125^\circ\text{C}$		0.7	1	$\mu\text{V}/^\circ\text{C}$
<b>OUTPUT CHARACTERISTICS</b>						
Output Voltage High	$V_{OH}$	$R_L = 2\text{ k}\Omega$ to ground $-40^\circ\text{C} \leq T_A \leq +125^\circ\text{C}$	3.7	3.9		V
Output Voltage Low	$V_{OL}$	$R_L = 2\text{ k}\Omega$ to ground $-40^\circ\text{C} \leq T_A \leq +125^\circ\text{C}$	3.4	3.6		V
Short Circuit Limit	$I_{SC}$	$-40^\circ\text{C} \leq T_A \leq +125^\circ\text{C}$		25	-3.6	mA
Output Current	$I_O$	$V_{OUT} = \pm 3.6\text{ V}$ $-40^\circ\text{C} \leq T_A \leq +125^\circ\text{C}$		$\pm 10$	-3.5	mA
<b>POWER SUPPLY</b>						
Power Supply Rejection Ratio	PSRR	$V_S = \pm 5.0\text{ V to } \pm 15.0\text{ V}$ $-40^\circ\text{C} \leq T_A \leq +125^\circ\text{C}$	110	118		dB
Supply Current/Amplifier	$I_{SY}$	$-40^\circ\text{C} \leq T_A \leq +125^\circ\text{C}$	110		1.7	mA
					2.0	mA
<b>DYNAMIC PERFORMANCE</b>						
Slew Rate	SR	$R_L = 2\text{ k}\Omega$ to ground		2.7		V/ $\mu\text{s}$
Gain Bandwidth Product	GBP			12		MHz
<b>NOISE PERFORMANCE</b>						
Voltage Noise	$e_{n\text{ p-p}}$	0.1 Hz to 10 Hz		0.1		$\mu\text{V p-p}$
Voltage Noise Density	$e_n$	$f = 1\text{ kHz}$		1.8		nV/ $\sqrt{\text{Hz}}$
Current Noise Density	$i_n$	$f = 10\text{ Hz}$		3.5		pA/ $\sqrt{\text{Hz}}$
Current Noise Density	$i_n$	$f = 200\text{ Hz}$		1.2		pA/ $\sqrt{\text{Hz}}$

$V_S = \pm 15\text{ V}$ ,  $V_{CM} = 0\text{ V}$ ,  $T_A = +25^\circ\text{C}$ , unless otherwise specified.

Table 2.

Parameter	Symbol	Conditions	Min	Typ	Max	Unit
<b>INPUT CHARACTERISTICS</b>						
Offset Voltage	$V_{OS}$	$-40^\circ\text{C} \leq T_A \leq +125^\circ\text{C}$		40	125	$\mu\text{V}$
					270	$\mu\text{V}$
Input Bias Current	$I_B$	$-40^\circ\text{C} \leq T_A \leq +125^\circ\text{C}$		40	90	nA
					165	nA
Input Offset Current	$I_{OS}$	$-40^\circ\text{C} \leq T_A \leq +125^\circ\text{C}$			60	nA
					100	nA
Input Voltage Range			-12.5		+12.5	V
Common-Mode Rejection Ratio	CMRR	$V_{CM} = -12.5\text{ V to }+12.5\text{ V}$ $-40^\circ\text{C} \leq T_A \leq +125^\circ\text{C}$	110	113		dB
			100	104		dB
Open-Loop Gain	$A_{VO}$	$R_L = 2\text{ k}\Omega$ , $V_O = -12.5\text{ V to }+12.5\text{ V}$ $-40^\circ\text{C} \leq T_A \leq +125^\circ\text{C}$	500	1200		V/mV
			250	500		V/mV
Offset Voltage Drift	$\Delta V_{OS}/\Delta T$	$-40^\circ\text{C} \leq T_A \leq +125^\circ\text{C}$		0.7	1	$\mu\text{V}$
<b>OUTPUT CHARACTERISTICS</b>						
Output Voltage High	$V_{OH}$	$R_L = 2\text{ k}\Omega$ to ground $-40^\circ\text{C} \leq T_A \leq +125^\circ\text{C}$	13.4	13.6		V
			13.1	13.3		V
Output Voltage Low	$V_{OL}$	$R_L = 2\text{ k}\Omega$ to ground $-40^\circ\text{C} \leq T_A \leq +125^\circ\text{C}$		-13.3	-13.2	V
				-13.25	-13.18	V
Short Circuit Limit	$I_{SC}$		25			mA
Output Current	$I_O$	$V_{OUT} = \pm 13.6\text{ V}$		$\pm 10$		mA
<b>POWER SUPPLY</b>						
Power Supply Rejection Ratio	PSRR	$V_S = \pm 5.0\text{ V to } \pm 15.0\text{ V}$ $-40^\circ\text{C} \leq T_A \leq +125^\circ\text{C}$	110	118		dB
			110			dB
Supply Current/Amplifier	$I_{SY}$	$-40^\circ\text{C} \leq T_A \leq +125^\circ\text{C}$			1.775	mA
					2.10	mA
<b>DYNAMIC PERFORMANCE</b>						
Slew Rate	SR	$R_L = 2\text{ k}\Omega$ to ground		2.7		V/ $\mu\text{s}$
Gain Bandwidth Product	GBP			12		MHz
<b>NOISE PERFORMANCE</b>						
Voltage Noise	$e_{n\text{ p-p}}$	0.1 Hz to 10 Hz		0.15		$\mu\text{V p-p}$
Voltage Noise Density	$e_n$	$f = 1\text{ kHz}$		1.8		nV/ $\sqrt{\text{Hz}}$
Current Noise Density	$i_n$	$f = 10\text{ Hz}$		3.5		pA/ $\sqrt{\text{Hz}}$
Current Noise Density	$i_n$	$f = 200\text{ Hz}$		1.2		pA/ $\sqrt{\text{Hz}}$

**ABSOLUTE MAXIMUM RATINGS**

Table 3.

Parameter	Rating
Supply Voltage	$\pm 18\text{ V}/+36\text{ V}$
Input Voltage	$\pm V$ supply
Differential Input Voltage	$\pm V$ supply
Output Short-Circuit Duration to GND	Indefinite
Storage Temperature Range	$-65^{\circ}\text{C}$ to $+150^{\circ}\text{C}$
Operating Temperature Range	$-40^{\circ}\text{C}$ to $+125^{\circ}\text{C}$
Junction Temperature Range	$-65^{\circ}\text{C}$ to $+150^{\circ}\text{C}$
Lead Temperature (Soldering 60 sec)	$300^{\circ}\text{C}$

Stresses above those listed under Absolute Maximum Ratings may cause permanent damage to the device. This is a stress rating only; functional operation of the device at these or any other conditions above those indicated in the operational section of this specification is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.